

Digital Transistors (Built-in Resistors)

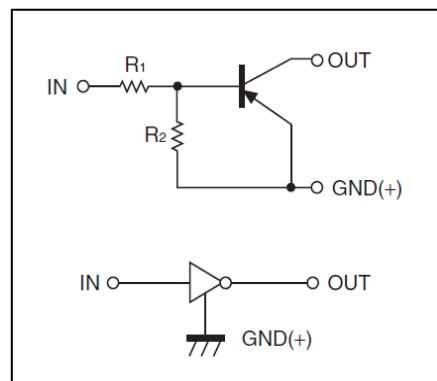
DTA124EM/DTA124EE/DTA124EUA DTA124EKA /DTA124ECA/DTA124ESA

DIGITAL TRANSISTOR (PNP)

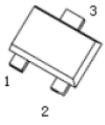
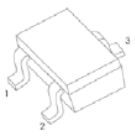
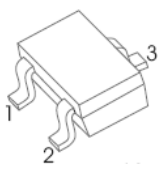
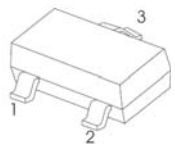
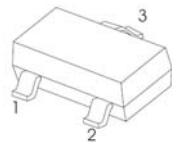

FEATURES

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors(see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input.They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy

• Equivalent Circuit



PIN CONNENCTIONS and MARKING

<p>DTA124EM</p>  <p>SOT-723</p> <p>1. IN 2. GND 3. OUT</p> <p>MARKING:15</p>	<p>DTA124EE</p>  <p>SOT-523</p> <p>1. IN 2. GND 3. OUT</p> <p>MARKING:15</p>
<p>DTA124EUA</p>  <p>SOT-323</p> <p>1. IN 2. GND 3. OUT</p> <p>MARKING:15</p>	<p>DTA124EKA</p>  <p>SOT-23-3L</p> <p>1. IN 2. GND 3. OUT</p> <p>MARKING:15</p>
<p>DTA124ECA</p>  <p>SOT-23</p> <p>1.IN 2.GND 3.OUT</p> <p>MARKING:15</p>	<p>DTA124ESA</p>  <p>TO-92S</p> <p>1. GND 2. OUT 3. IN</p>

MAXIMUM RATINGS(Ta=25°C unless otherwise noted)

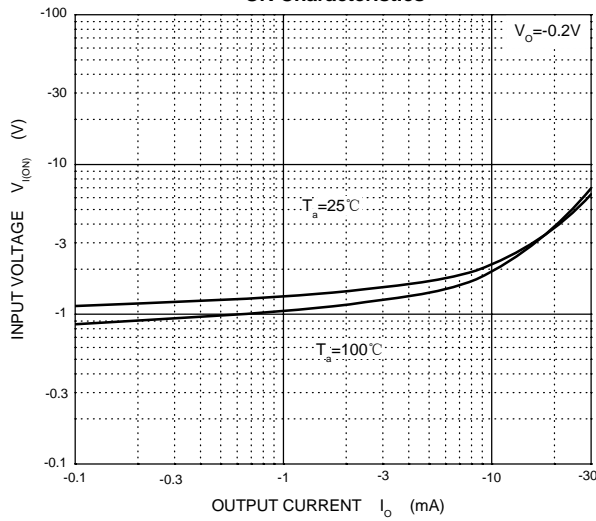
Symbol	Parameter	Limits(DTA124E□)						Unit
		M	E	UA	KA	CA	SA	
V _{CC}	Supply Voltage	-50						V
V _{IN}	Input Voltage	-40~+10						V
I _O	Output Current	-30						mA
I _{CM}	Peak Collector Current	-100						mA
P _D	Power Dissipation	100	150	200	200	200	300	mW
T _J	Junction Temperature	150						°C
T _{stg}	Storage Temperature	-55~+150						°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

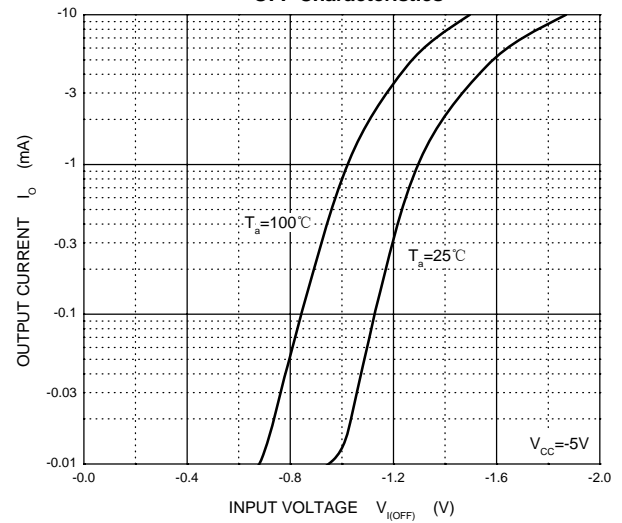
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input voltage	V _{I(off)}	V _{CC} =-5V, I _O =-100μA	-0.5			V
	V _{I(on)}	V _O =-0.2V, I _O =-5 mA			-3	V
Output voltage	V _{O(on)}	I _O /I _I =-10mA/-0.5mA			-0.3	V
Input current	I _I	V _I =-5V			-0.36	mA
Output current	I _{O(off)}	V _{CC} =-50V, V _I =0			-0.5	μA
DC current gain	G _I	V _O =-5V, I _O =-5mA	56			
Input resistance	R ₁		15.4	22	28.6	kΩ
Resistance ratio	R ₂ /R ₁		0.8	1	1.2	
Transition frequency	f _T	V _O =-10V, I _O =-5mA, f=100MHz		250		MHz



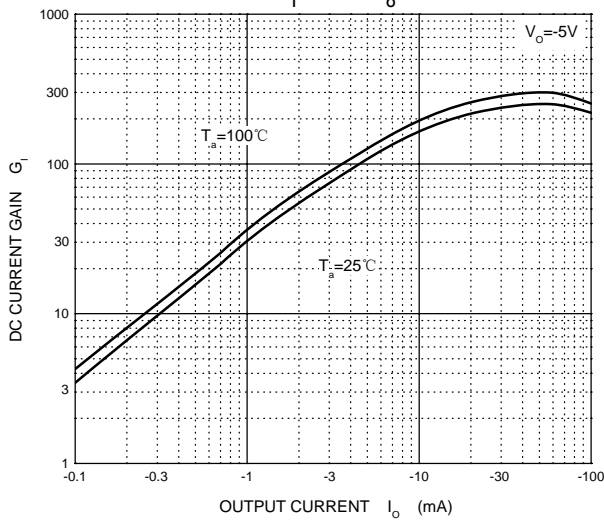
ON Characteristics



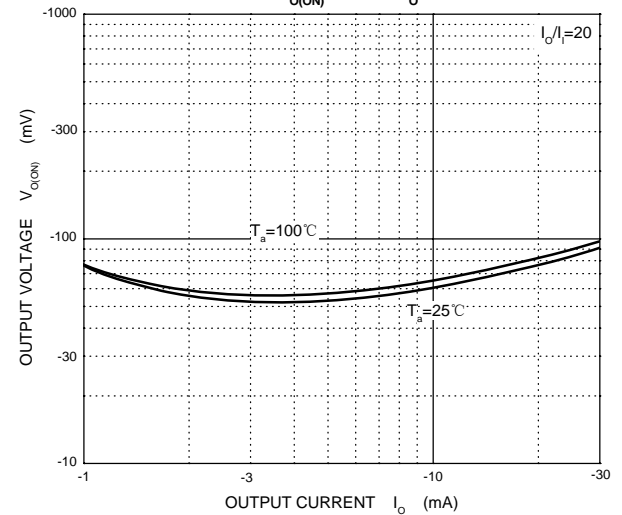
OFF Characteristics



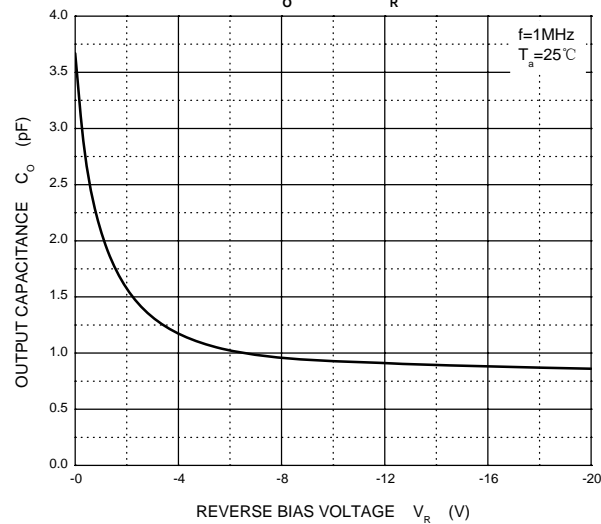
$G_I - I_O$



$V_{O(ON)} - I_O$



$C_O - V_R$



$P_D - T_a$

